Full Bridge Rectifier

Dual 20 V N-Channel with dual 3.2 A Schottky Barrier Diode, 4.0 x 4.0 x 0.5 mm µCool[™] Package

Features

- Full-Bridge Rectifier Block
- Up to 3.2 A operation
- Low R_{DS(on}) MOSFET to minimize conduction loss
- Low gate charge MOSFET
- Low VF Schottky diode
- Ultra Low Inductance Package
- This Device uses Halogen-Free Molding Compound
- These are Pb-Free Devices

Applications

- Wireless Charging
- AC–DC Rectification
- Optimized for Power Management Applications for Portable Products, such as Cell Phones, PMP, DSC, GPS, and others

Parameter	Symbol	Value	Unit	
Input voltage between two MOSFET drain		V _{LL}	20	V
Bridge Operating Junction an Temperature	T _J , T _{STG}	–55 to 125	°C	
Lead Temperature for Solder (1/8" from case for 10 s)	ing Purposes	ΤL	260	°C
Continuous Drain Current	$T_A = 25^{\circ}C$	۱ ₀	2.2	А
R_JA (NOTE 1)	T _A = 85°C		1.16	
Power Dissipation R_JA (Note 1)	T _A = 25°C	PD	1.2	W
	T _A = 85°C		0.47	
Continuous Drain Current	T _A = 25°C	۱ ₀	3.2	Α
$R_JA t < 5 s (Note 1)$	T _A = 85°C		1.88	
Power Dissipation	T _A = 25°C	PD	2.34	W
$R_JA t < 5 s (Note T)$	$T_A = 85^{\circ}C$		0.94	
Continuous Drain Current	$T_A = 25^{\circ}C$	Ι _Ο	1.16	А
R_JA (Note 2)	$T_A = 85^{\circ}C$		0.6	
Power Dissipation	T _A = 25°C	PD	0.47	W
	T _A = 85°C		0.185	

RECTIFIER MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
2. Surface-mounted on FR4 board using the minimum recommended pad size

of 30 mm², 2 oz. Cu.



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V(BR)DSS

MOSFET R_{DS(on)} TYP I_D MAX

20 V		3.2 A
	17 mΩ @ 10 V	

V _R WAX	VFITP	
20 V	0.45 V	3.2 A



RECTIFIER

4.0 4.0 mm µCool Pin Connections (Top View)





Vout b ' Vout Vout GND1 с¦ d GND2 '∾ ¦ ⊏ GND2 GND1 (Top View)

ORDERING INFORMATION						
Device	Package	Shipping [†]				
NMLU1210TWG	UDFN (Pb-Free)	3000 / Tape & Reel				

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit
Junction-to-Ambient - Steady State (Note 3)	R _{θJA}	82.5	°C/W
Junction-to-Ambient – t \leq 5 s (Note 3)	R _{θJA}	42.5	
Junction-to-Ambient - Steady State min Pad (Note 4)	$R_{\theta JA}$	209	

Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
 Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm², 2 oz. Cu.

BRIDGE ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise specified)

Parameter	Symbol	Test Condition		Тур	Max	Unit
ON CHARACTERISTICS						
Rectifying Forward Voltage (Note 5)	V _{fd2}	Input voltage V _{LL} = \pm 5 V; The output current of Rectifier I _{out} = 2 A		0.45	.56	V
Rectifier leakage current	I _{leak}	Input voltage $V_{LL} = 16 V$; No Load on the Rectifier output		31	1000	uA
Rectifier Reverse leakage current	I _{rleak}	Input voltage V _{LL} = 0 V; The output voltage of the Rectifier V _{out} = 5 V		21	1000	uA

5. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%

MOSFET ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test Conditi	on	Min	Тур	Max	Unit
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = VDS, I_D =$	250 μΑ	1.2		2.2	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} / T _J				4		mV/°C
Drain-to-Source On Resistance (Note 6)	D	V_{GS} = 10 V, I _D = 3.2 A			17	26	
	RDS(on)	V_{GS} = 4.5 V, I _D = 3.2 A			23	32	11152
Forward Transconductance	9 _{FS}	$VDS = 10 \text{ V}, \text{ I}_{\text{D}} = 2.0 \text{ A}$			3.5		S
DRAIN-SOURCE DIODE CHARACT	ERISTICS						
Forward Diode Voltage (Note 6)	V _{SD}	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 2.0 \text{ A}$	$T_J = 25^{\circ}C$		0.79		V

T_J = 125°C

0.65

6. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%

SCHOTTKY DIODE ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Maximum Instantaneous Forward	V _F	I _F = 1.0 A		0.36		V
Voltage (Note 7)		I _F = 2.0 A		0.41		
Maximum Instantaneous Reverse Current	۱ _R	V _R = 20 V		0.04		mA

7. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%

SCHOTTKY DIODE ELECTRICAL CHARACTERISTICS (T_J = 100°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Maximum Instantaneous Forward	¥-	I _F = 1.0 A		0.29		V
Voltage (Note 8)	٧F	I _F = 2.0 A		0.36		
Maximum Instantaneous Reverse Current	I _R	V _R = 20 V		4		mA

8. Pulse Test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2%

9. For detailed MOSFET and Diode parameters, please refer to the ON Semiconductor datasheets of NTTFS4930N and MBR230LSFT1G. The test on each individual die is limited to the system package.



GND1 and GND2 are not internally connected. The user should make the connection in the PCB design.

TYPICAL PERFORMANCE CURVES

 $(T_J = 25^{\circ}C \text{ unless otherwise specified})$



TYPICAL PERFORMANCE CURVES

(T_J = 25°C unless otherwise specified)



PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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